## 74HC165-Q100; 74HCT165-Q100

# 8-bit parallel-in/serial out shift register Rev. 2 — 21 August 2017

Product data sheet

## **General description**

The 74HC165-Q100; 74HCT165-Q100 are 8-bit serial or parallel-in/serial-out shift registers. The device features a serial data input (DS), eight parallel data inputs (D0 to D7) and two complementary serial outputs (Q7 and  $\overline{\rm Q7}$ ). When the parallel load input  $(\overline{PL})$  is LOW the data from D0 to D7 is loaded into the shift register asynchronously. When PL is HIGH data enters the register serially at DS. When the clock enable input (CE) is LOW data is shifted on the LOW-to-HIGH transitions of the CP input. A HIGH on CE will disable the CP input. Inputs are overvoltage tolerant to 15 V. This enables the device to be used in HIGH-to-LOW level shifting applications.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

#### 2 Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Asynchronous 8-bit parallel load
- Synchronous serial input
- Complies with JEDEC standard no. 7A
- Input levels:
  - For 74HC165-Q100: CMOS level
  - For 74HCT165-Q100: TTL level
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0  $\Omega$ )

## **Applications**

Parallel-to-serial data conversion

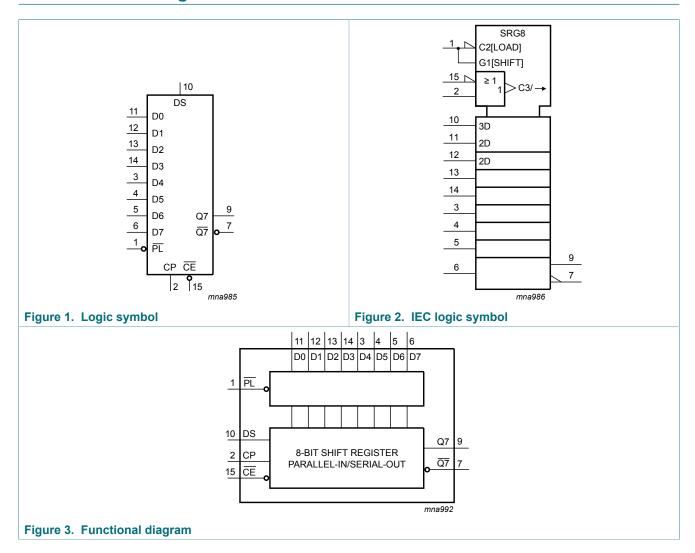


## 4 Ordering information

**Table 1. Ordering information** 

Type number	Package										
	Temperature range	Name	Description	Version							
74HC165D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1							
74HCT165D-Q100			body width 3.9 mm								
74HC165PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1							
74HCT165PW-Q100			body width 4.4 mm								
74HC165BQ-Q100	-40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced	SOT763-1							
74HCT165BQ-Q100			very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm								

## 5 Functional diagram



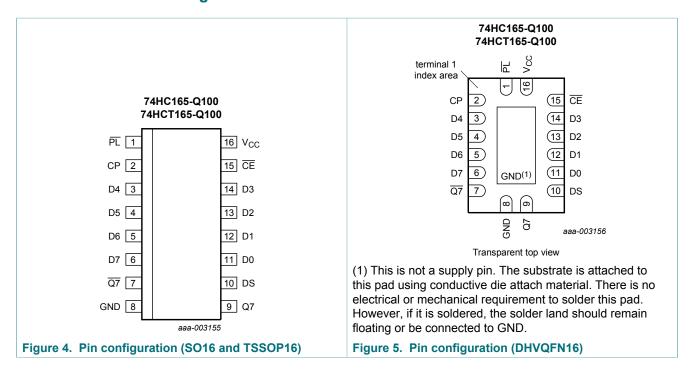
74HC\_HCT165\_Q100

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## 6 Pinning information

#### 6.1 Pinning



#### 6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
PL	1	asynchronous parallel load input (active LOW)
СР	2	clock input (LOW-to-HIGH edge-triggered)
Q7	7	complementary output from the last stage
GND	8	ground (0 V)
Q7	9	serial output from the last stage
DS	10	serial data input
D0 to D7	11, 12, 13, 14, 3, 4, 5, 6	parallel data inputs (also referred to as Dn)
CE	15	clock enable input (active LOW)
V <sub>CC</sub>	16	positive supply voltage

## 7 Functional description

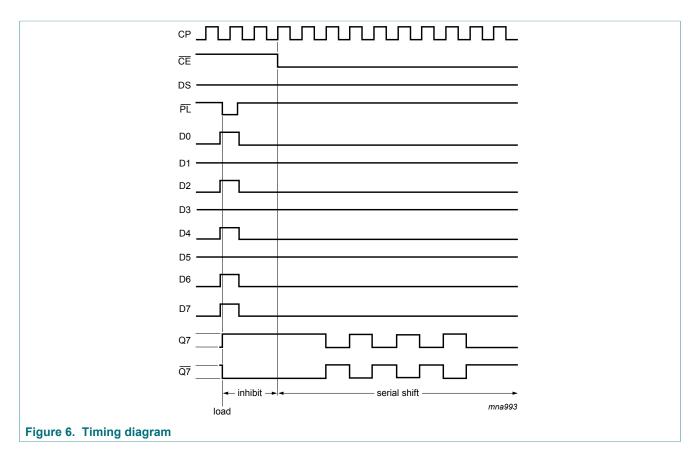
Table 3. Function table [1]

Operating modes	Inputs					Qn regis	ters	Outputs	
	PL	CE	СР	DS	D0 to D7	Q0	Q1 to Q6	Q7	<b>Q7</b>
parallel load	L	Х	Х	X	L	L	L to L	L	Н
	L	Х	Х	X	Н	Н	H to H	Н	L
serial shift	Н	L	1	I	X	L	q0 to q5	q6	<del>q</del> 6
	Н	L	1	h	X	Н	q0 to q5	q6	<del>q</del> 6
	Н	1	L	I	X	L	q0 to q5	q6	<del>q</del> 6
	Н	1	L	h	Х	Н	q0 to q5	q6	<del>q</del> 6
hold "do nothing"	Н	Н	Х	X	Х	q0	q1 to q6	q7	<del>q7</del>
l	Н	X	Н	X	X	q0	q1 to q6	q7	<del>q7</del>

<sup>[1]</sup> H = HIGH voltage level;

h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

 $<sup>\</sup>uparrow$  = LOW-to-HIGH clock transition.



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L = LOW voltage level;

I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

q = state of the referenced output one set-up time prior to the LOW-to-HIGH clock transition;

X = don't care;

## 8 Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V)

		, , ,				•
Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	[1]	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_{O}$ < -0.5 V or $V_{O}$ > $V_{CC}$ + 0.5 V	[1]	-	±20	mA
lo	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$		-	±25	mA
I <sub>CC</sub>	supply current			-	50	mA
$I_{GND}$	ground current			-50	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C	[2]	-	500	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 9 Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74F	IC165-Q	100	74H	Unit		
			Min	Тур	Max	Min	Тур	Max	
$V_{CC}$	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V <sub>CC</sub> = 6.0 V	-	-	83	-	-	-	ns/V

<sup>[2]</sup> For SO16 Packages: P<sub>tot</sub> derates linearly with 8 mW/K above 70 °C. For TSSOP16 Packages: P<sub>tot</sub> derates linearly with 5.5 mW/K above 60 °C. For DHVQFN16 Packages: P<sub>tot</sub> derates linearly with 4.5 mW/K above 60 °C.

### 10 Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C			°C to	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC165	-Q100									
$V_{IH}$	HIGH-level input	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
$V_{IL}$	LOW-level input	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	voltage	V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
$V_{OH}$	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HCT16	5-Q100							l	1	
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	8.0	V
V <sub>OH</sub>	V <sub>OH</sub> HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
		Ι <sub>Ο</sub> = -20 μΑ	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	-	80	-	160	μΑ
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$ ; other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V								
		Dn and DS inputs	-	35	126	-	157.5	-	171.5	μΑ
		CP CE, and PL inputs	-	65	234	-	292.5	-	318.5	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

## 11 Dynamic characteristics

#### **Table 7. Dynamic characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $C_L = 50 \text{ pF}$  unless otherwise specified; for test circuit, see Figure 12

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC165	-Q100									
t <sub>pd</sub>	propagation delay	CP or $\overline{CE}$ to Q7, $\overline{Q7}$ ; see Figure 7								
		V <sub>CC</sub> = 2.0 V	-	52	165	-	205	-	250	ns
		V <sub>CC</sub> = 4.5 V	-	19	33	-	41	-	50	ns
		V <sub>CC</sub> = 6.0 V	-	15	28	-	35	-	43	ns
		$V_{CC}$ = 5.0 V; $C_L$ = 15 pF	-	16	-	-	-	-	-	ns
		PL to Q7, Q7; see Figure 8								
		V <sub>CC</sub> = 2.0 V	-	50	165	-	205	-	250	ns
		V <sub>CC</sub> = 4.5 V	-	18	33	-	41	-	50	ns
		V <sub>CC</sub> = 6.0 V	-	14	28	-	35	-	43	ns
		$V_{CC}$ = 5.0 V; $C_L$ = 15 pF	-	15	-	-	-	-	-	ns
		D7 to Q7, Q7; see Figure 9								
		V <sub>CC</sub> = 2.0 V	-	36	120	-	150	-	180	ns
		V <sub>CC</sub> = 4.5 V	-	13	24	-	30	-	36	ns
		V <sub>CC</sub> = 6.0 V	-	10	20	-	26	-	31	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	11	-	-	-	-	-	ns
t <sub>t</sub>	transition time	Q7, Q7 output; see Figure 7 [2]								
		V <sub>CC</sub> = 2.0 V	-	19	75	-	95	-	110	ns
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	-	16	-	19	ns
t <sub>W</sub>	pulse width	CP input HIGH or LOW; see Figure 7								
		V <sub>CC</sub> = 2.0 V	80	17	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	6	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	5	-	17	-	20	-	ns
		PL input LOW; see Figure 8								
		V <sub>CC</sub> = 2.0 V	80	14	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	5	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	4	-	17	-	20	-	ns

Symbol	Parameter	Conditions		25 °C			°C to	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>rec</sub>	recovery time	PL to CP, CE; see Figure 8								
		V <sub>CC</sub> = 2.0 V	100	22	-	125	-	150	-	ns
		V <sub>CC</sub> = 4.5 V	20	8	-	25	-	30	-	ns
		V <sub>CC</sub> = 6.0 V	17	6	-	21	-	26	-	ns
t <sub>su</sub>	set-up time	DS to CP, CE; see Figure 10								
		V <sub>CC</sub> = 2.0 V	80	11	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	4	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	3	-	17	-	20	-	ns
		CE to CP and CP to CE; see Figure 10								
		V <sub>CC</sub> = 2.0 V	80	17	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	6	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	5	-	17	-	20	-	ns
		Dn to PL; see Figure 11								
		V <sub>CC</sub> = 2.0 V	80	22	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	8	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	6	-	17	-	20	-	ns
t <sub>h</sub>	hold time	DS to CP, $\overline{\text{CE}}$ and Dn to $\overline{\text{PL}}$ ; see Figure 10								
		V <sub>CC</sub> = 2.0 V	5	2	-	5	-	5	-	ns
		V <sub>CC</sub> = 4.5 V	5	2	-	5	-	5	-	ns
		V <sub>CC</sub> = 6.0 V	5	2	-	5	-	5	-	ns
		CE to CP and CP to CE; see Figure 10								
		V <sub>CC</sub> = 2.0 V	5	-17	-	5	-	5	-	ns
		V <sub>CC</sub> = 4.5 V	5	-6	-	5	-	5	-	ns
		V <sub>CC</sub> = 6.0 V	5	-5	-	5	-	5	-	ns
f <sub>max</sub>	maximum	CP input; see Figure 7								
	frequency	V <sub>CC</sub> = 2.0 V	6	17	-	5	-	4	-	MHz
		V <sub>CC</sub> = 4.5 V	30	51	-	24	-	20	-	MHz
		V <sub>CC</sub> = 6.0 V	35	61	-	28	-	24	-	MHz
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	56	-	-	-	-	-	MHz
C <sub>PD</sub>	power dissipation capacitance	per package; $V_I = GND$ to $V_{CC}$ [3]	-	35	-	-	-	-	-	pF

Symbol	Parameter	Conditions		25 °C			°C to	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HCT16	5-Q100			'	·	ı	'		'	
t <sub>pd</sub>	propagation delay	CE, CP to Q7, Q7; see Figure 7								
		V <sub>CC</sub> = 4.5 V	-	17	34	-	43	-	51	ns
		$V_{CC}$ = 5.0 V; $C_L$ = 15 pF	-	14	-	-	-	-	-	ns
		PL to Q7, Q7; see Figure 8								
		V <sub>CC</sub> = 4.5 V	-	20	40	-	50	-	60	ns
		$V_{CC}$ = 5.0 V; $C_L$ = 15 pF	-	17	-	-	-	-	-	ns
		D7 to Q7, Q7; see Figure 9								
		V <sub>CC</sub> = 4.5 V	-	14	28	-	35	-	42	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	11	-	-	-	-	-	ns
t <sub>t</sub>	transition time	Q7, Q7 output; see Figure 7 [2]								
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
t <sub>W</sub>	pulse width	CP input; see Figure 7								
		V <sub>CC</sub> = 4.5 V	16	6	-	20	-	24	-	ns
		PL input; see Figure 8								
		V <sub>CC</sub> = 4.5 V	20	9	-	25	-	30	-	ns
t <sub>rec</sub>	recovery time	PL to CP, CE; see Figure 8								
		V <sub>CC</sub> = 4.5 V	20	8	-	25	-	30	-	ns
t <sub>su</sub>	set-up time	DS to CP, CE; see Figure 10								
		V <sub>CC</sub> = 4.5 V	20	2	-	25	-	30	-	ns
		CE to CP and CP to CE; see Figure 10								
		V <sub>CC</sub> = 4.5 V	20	7	-	25	-	30	-	ns
		Dn to PL; see Figure 11								
		V <sub>CC</sub> = 4.5 V	20	10	-	25	-	30	-	ns
t <sub>h</sub>	hold time	DS to CP, CE and Dn to PL; see Figure 10								
		V <sub>CC</sub> = 4.5 V	7	-1	-	9	-	11	-	ns
		CE to CP and CP to CE; see Figure 10								
		V <sub>CC</sub> = 4.5 V	0	-7	-	0	-	0	-	ns

Symbol	Parameter	Parameter Conditions		25 °C			C to	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
f <sub>max</sub>	maximum	CP input; see Figure 7								
	frequency	V <sub>CC</sub> = 4.5 V	26	44	-	21	-	17	-	MHz
		$V_{CC}$ = 5.0 V; $C_L$ = 15 pF	-	48	-	-	-	-	-	MHz
C <sub>PD</sub>	power dissipation capacitance	per package; [3] V <sub>I</sub> = GND to V <sub>CC</sub> - 1.5 V	-	35	-	-	-	-	-	pF

- [2]
- $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).  $P_D = C_{PD} \times V_{CC}^2 \times f_1 + \Sigma (C_L \times V_{CC}^2 \times f_0)$  where:

f<sub>i</sub> = input frequency in MHz;

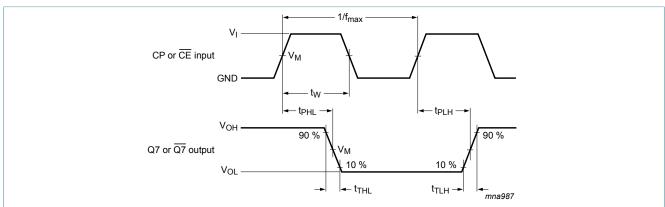
f<sub>o</sub> = output frequency in MHz;

 $\Sigma (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs};$ 

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V.

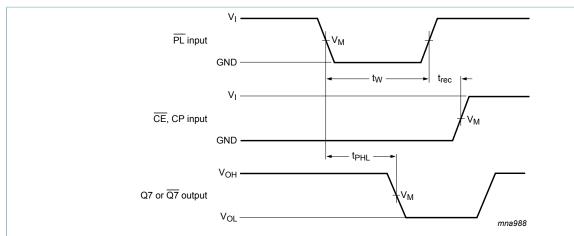
#### 11.1 Waveforms and test circuit



Measurement points are given in Table 8.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

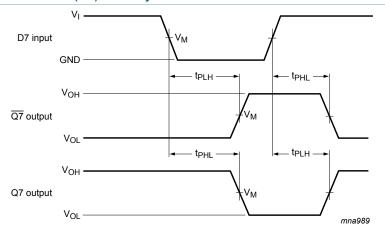
Figure 7. The clock (CP) or clock enable ( $\overline{CE}$ ) to output (Q7 or  $\overline{Q7}$ ) propagation delays, the clock pulse width, the maximum clock frequency and the output transition times



Measurement points are given in Table 8.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

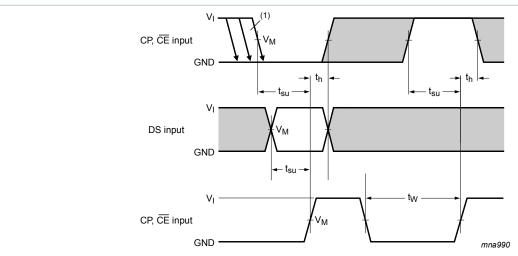
Figure 8. The parallel load ( $\overline{PL}$ ) pulse width, the parallel load to output (Q7 or  $\overline{Q7}$ ) propagation delays, the parallel load to clock (CP) and clock enable ( $\overline{CE}$ ) recovery time



Measurement points are given in Table 8.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

Figure 9. The data input (D7) to output (Q7 or Q7) propagation delays when PL is LOW

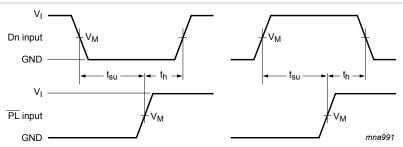


(1)  $\overline{\text{CE}}$  may change only from HIGH-to-LOW while CP is LOW.

The shaded areas indicate when the input is permitted to change for predictable output performance Measurement points are given in <u>Table 8</u>.

V<sub>OL</sub> and V<sub>OH</sub> are typical voltage output levels that occur with the output load.

Figure 10. The set-up and hold times from the serial data input (DS) to the clock (CP) and clock enable ( $\overline{CE}$ ) inputs, from the clock enable input ( $\overline{CE}$ ) to the clock input (CP) and from the clock input (CP) to the clock enable input ( $\overline{CE}$ )



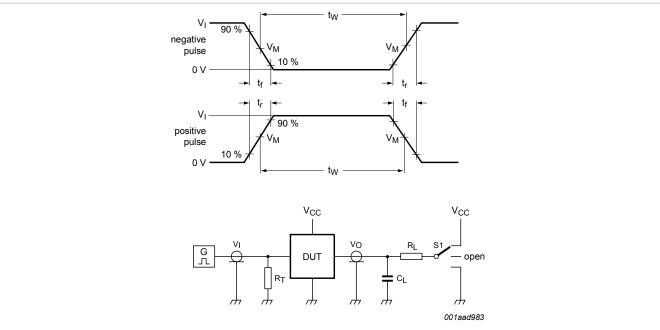
Measurement points are given in Table 8.

V<sub>OL</sub> and V<sub>OH</sub> are typical voltage output levels that occur with the output load.

Figure 11. The set-up and hold times from the data inputs (Dn) to the parallel load input (PL)

Table 8. Measurement points

Туре	Input		Output
	VI	V <sub>M</sub>	V <sub>M</sub>
74HC165-Q100	V <sub>CC</sub>	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
74HCT165-Q100	3 V	1.3 V	1.3 V



Test data is given in Table 9.

Definitions for test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

 $C_L$  = Load capacitance including jig and probe capacitance.

R<sub>L</sub> = Load resistance.

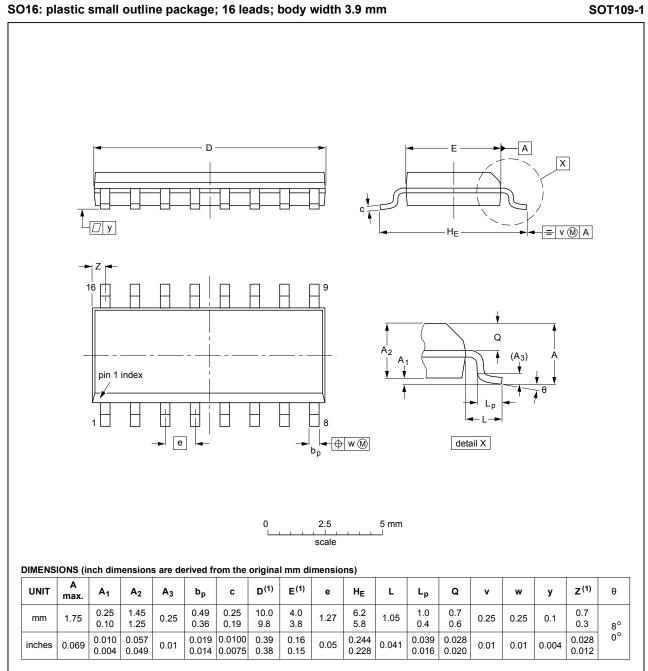
S1 = Test selection switch

Figure 12. Test circuit for measuring switching times

Table 9. Test data

Туре	Input		Load	S1 position		
	VI	t <sub>r</sub> , t <sub>f</sub>	C <sub>L</sub>	$R_L$	t <sub>PHL</sub> , t <sub>PLH</sub>	
74HC165-Q100	V <sub>CC</sub>	6 ns	15 pF, 50 pF	1 kΩ	open	
74HCT165-Q100	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	

## 12 Package outline



#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

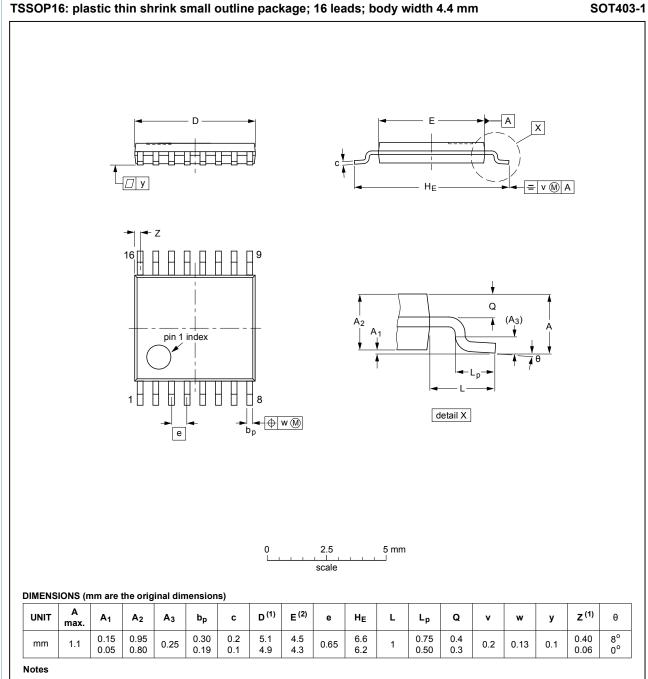
OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19

Figure 13. Package outline SOT109-1 (SO16)

74HC\_HCT165\_Q100

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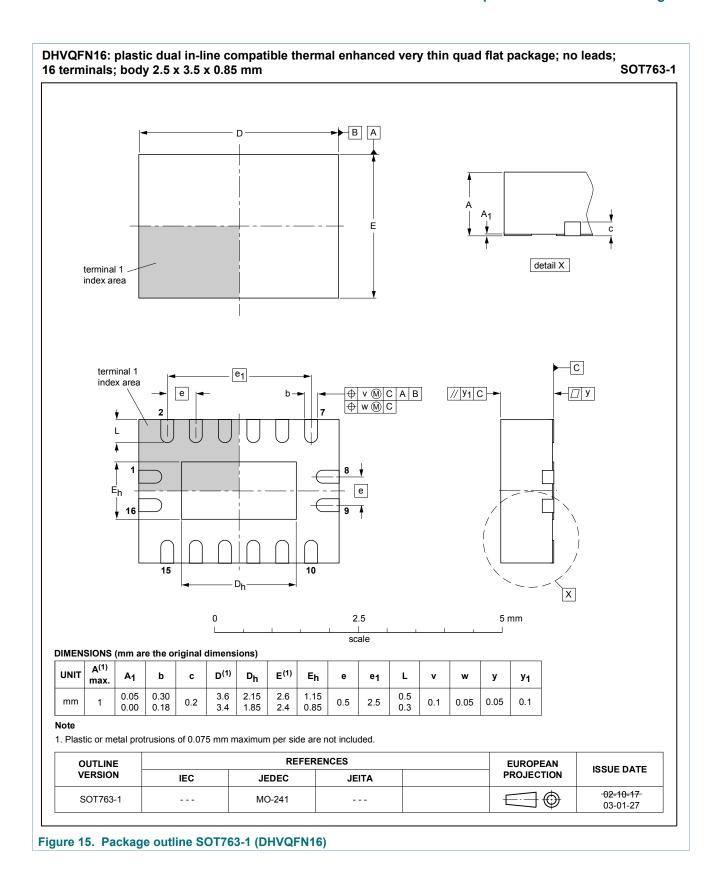
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- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT403-1		MO-153				<del>-99-12-27-</del> 03-02-18

Figure 14. Package outline SOT403-1 (TSSOP16)



74HC\_HCT165\_Q100

### 13 Abbreviations

#### Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

## 14 Revision history

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT165_Q100 v.2	20170821	Product data sheet	-	74HC_HCT165_Q100 v.1		
Modifications:	<ul> <li>General description updated.</li> <li>Hold time for 74HC165-Q100 has been updated.</li> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>					
74HC_HCT165_Q100 v.1	20120717	Product data sheet	-	-		

## 15 Legal information

#### 15.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- The term 'short data sheet' is explained in section "Definitions".
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